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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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2SK1526, 2SK1527 Silicon N Channel MOS FET

REJ03G0950-0300 Rev.3.00 May 13, 2009

Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown •
- Suitable for switching regulator and DC-DC converter •

Outline

Juc RENESAS Package code: PRSS0004ZF-A (Package name: TO-3PL) γD

1. Gate 2. Drain 3. Source

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Absolute Maximum Ratings

				$(Ta = 25^{\circ}C)$
Item		Symbol	Ratings	Unit
Drain to source voltage	2SK1526	V _{DSS}	450	V
	2SK1527		500	
Gate to source voltage		V _{GSS}	±30	V
Drain current		ID	40	А
Drain peak current		I _{D(pulse)} * ¹	160	А
Body to drain diode reverse drain current		I _{DR}	40	А
Channel dissipation		Pch* ²	250	W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. $PW \le 10 \propto s$, duty cycle $\le 1\%$

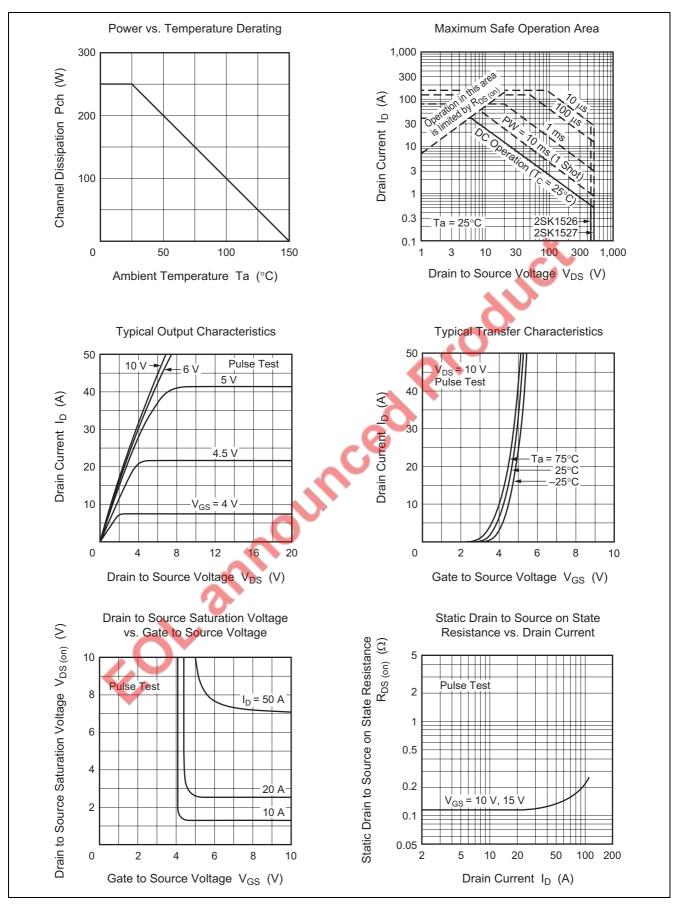
2. Value at $T_C = 25^{\circ}C$

Electrical Characteristics

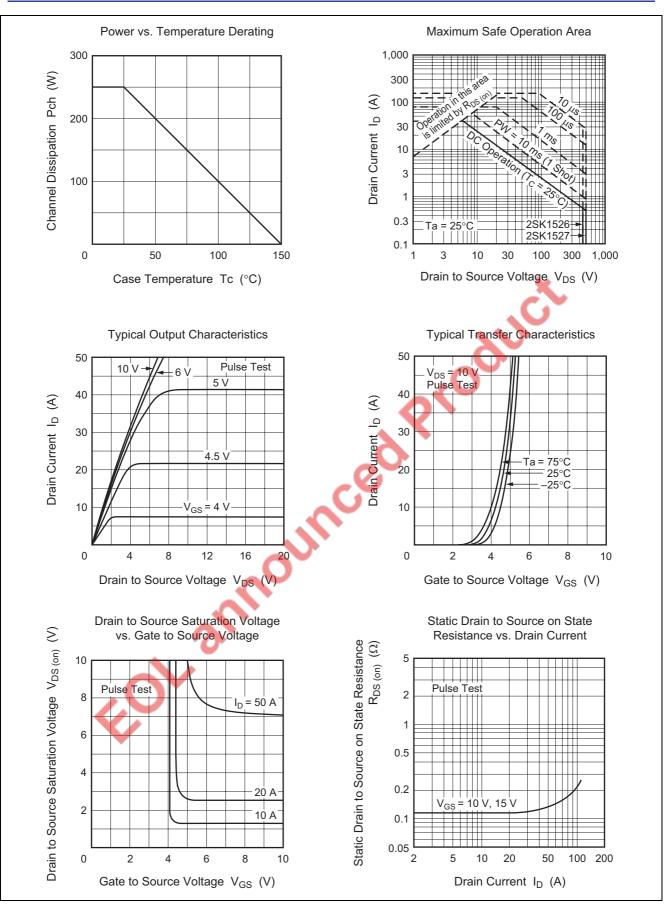
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Gate to source leak currentIGSS $ \pm 10$ $\circ A$ $V_{GS} = \pm 25$ V, $V_{DS} = 0$ Zero gate voltage drain current $2SK1526$ IDSS 250 $\circ A$ $V_{DS} = 360$ V, $V_{GS} = 0$ Gate to source cutoff voltage $V_{GS}(off)$ 2.0 3.0 VID = 1 mA, $V_{DS} = 10$ VStatic drain to source on state resistance $2SK1526$ $R_{DS}(on)$ 0.11 0.15 Ω ID = 20 A, $V_{GS} = 10$ V *3Forward transfer admittance $ y_{TS} $ 20 30 SID = 20 A, $V_{DS} = 10$ V *3Input capacitanceCiss 5800 pF $V_{DS} = 10$ V, $V_{GS} = 0$,Output capacitanceCoss 1430 pF $V_{DS} = 10$ V, $V_{GS} = 0$,Turn-on delay time $t_d(on)$ 60 nsID = 20 A, $V_{GS} = 10$ V,Rise timetr 175 nsID = 20 A, $V_{GS} = 10$ V,Fall timetr 160 nsID = 20 A, $V_{GS} = 10$ V,Body to drain diode forward voltage V_{DF} 1.2 NIF = 40 A, $V_{GS} = 0$ Body to drain diode reverse recovery t_{rr} 600 nsIF = 40 A, $V_{GS} = 0$,
$ \begin{array}{c} \mbox{Zero gate voltage drain current} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c } \hline I_{DSS} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1526 \end{array} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c c } \hline ZSK1526 \\ \hline ZSK1527 \end{array} & \begin{tabular}{ c c c c c c c c c c c c c c c c c c c$
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Gate to source cutoff voltageV_GS(off)2.03.0VIp = 1 mA, Vps = 10 VStatic drain to source on state resistance $2SK1526$ $2SK1527$ $R_{DS(on)}$ $2SK1527$ 0.110.15 0.12 Ω Ip = 20 A, Vps = 10 V *3Forward transfer admittance $ y_{fs} $ 2030SIp = 20 A, Vps = 10 V *3Input capacitanceCiss5800pFVps = 10 V, Vgs = 0, Vps = 10 V *3Output capacitanceCiss5800pFVps = 10 V, Vgs = 0, Vps = 10 V, Vgs = 10 V, Vgs = 0, Vps =
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state resistance 2SK1527 0.12 0.16 Forward transfer admittance $ y_{fs} $ 20 30 S $I_D = 20 \text{ A}, V_{DS} = 10 \text{ V}^{*3}$ Input capacitance Ciss 5800 pF $V_{DS} = 10 \text{ V}, V_{GS} = 0,$ Output capacitance Coss 1430 pF $f = 1 \text{ MHz}$ Reverse transfer capacitance Crss 150 pF $f = 20 \text{ A}, V_{GS} = 0,$ Turn-on delay time $t_{d(on)}$ 600 ns $I_D = 20 \text{ A}, V_{GS} = 10 \text{ V},$ Rise time $t_d(on)$ 600 ns $I_D = 20 \text{ A}, V_{GS} = 10 \text{ V},$ Turn-off delay time $t_d(on)$ 600 ns $I_D = 20 \text{ A}, V_{GS} = 10 \text{ V},$ Fall time t_r 175 ns $I_D = 20 \text{ A}, V_{GS} = 0$ Body to drain diode forward voltage V_{DF} 160 ns $I_F = 40 \text{ A}, V_{GS} = 0,$ Body to drain diode reverse recovery t_{rrr} 600<
state resistance 2SK1527 0.12 0.16 Forward transfer admittance $ y_{fs} $ 20 30 S $I_D = 20 \text{ A}, V_{DS} = 10 \text{ V}^{*3}$ Input capacitance Ciss 5800 pF $V_{DS} = 10 \text{ V}, V_{GS} = 0,$ Output capacitance Coss 1430 pF $f = 1 \text{ MHz}$ Reverse transfer capacitance Crss 150 pF $f = 20 \text{ A}, V_{GS} = 0,$ Turn-on delay time $t_{d(on)}$ 600 ns $I_D = 20 \text{ A}, V_{GS} = 10 \text{ V},$ Rise time t_r 150 pF $I_D = 20 \text{ A}, V_{GS} = 10 \text{ V},$ Rise time $t_{d(on)}$ 600 ns $I_D = 20 \text{ A}, V_{GS} = 10 \text{ V},$ Rise time t_r 175 ns $I_D = 20 \text{ A}, V_{GS} = 10 \text{ V},$ Fall time t_r 175 ns $I_F = 40 \text{ A}, V_{GS} = 0$ $I_F = 40 \text{ A}, V_{GS} = 0,$ Body to drain diode forward voltage V_{DF}
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Reverse transfer capacitanceCrss-150-pFTurn-on delay time $t_{d(on)}$ -60-ns $l_D = 20 \text{ A}, \text{ V}_{GS} = 10 \text{ V},$ Rise time t_r -175-ns $R_L = 1.5 \Omega$ Turn-off delay time $t_{d(off)}$ -420-nsFall time t_f -160-nsBody to drain diode forward voltage V_{DF} -1.2-VBody to drain diode reverse recovery t_{rr} -600-ns
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Fall time t_f 160nsBody to drain diode forward voltage V_{DF} 1.2V $I_F = 40 \text{ A}, V_{GS} = 0$ Body to drain diode reverse recovery t_{rr} 600ns $I_F = 40 \text{ A}, V_{GS} = 0$,
Body to drain diode forward voltage V_{DF} 1.2 $V_{IF} = 40 \text{ A}, V_{GS} = 0$ Body to drain diode reverse recovery t_{rr} 600ns $I_F = 40 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery t_{rr} — 600 — ns $I_F = 40 \text{ A}, V_{GS} = 0,$
Note: 3. Pulse test
JA

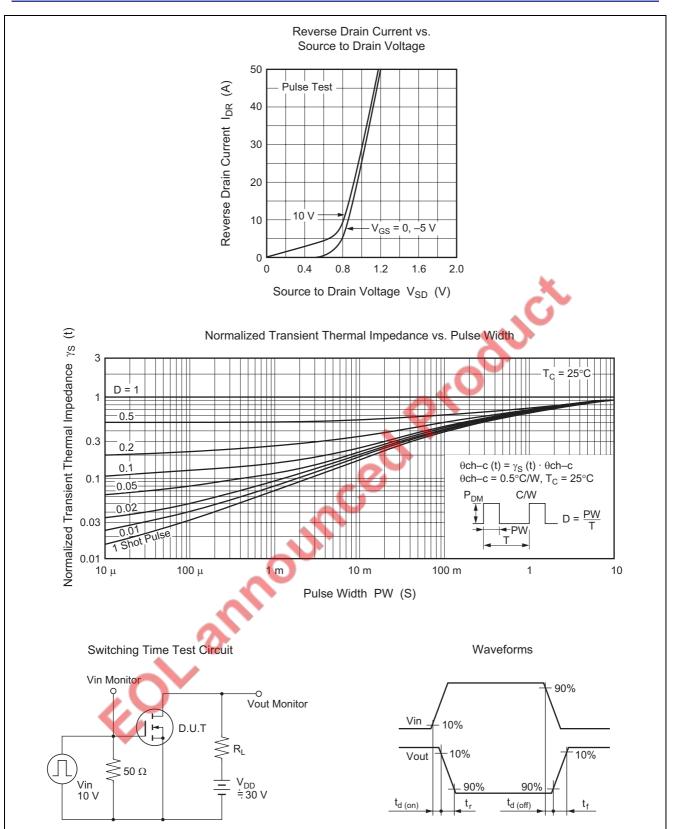
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Main Characteristics



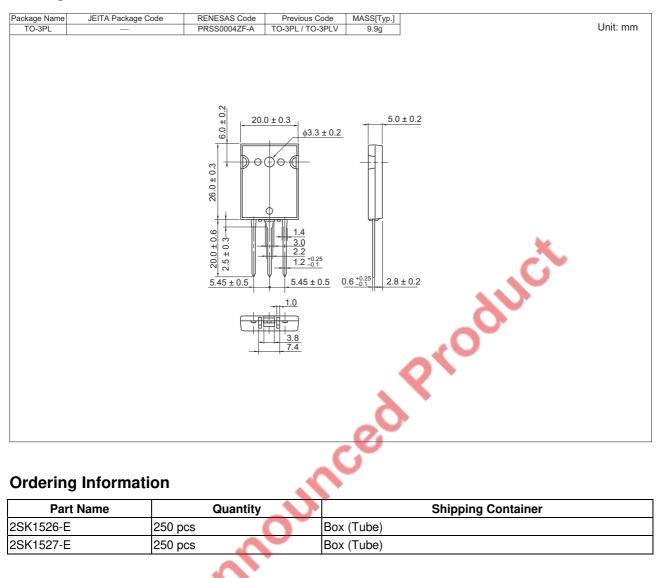
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Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SK1526-E	250 pcs	Box (Tube)
2SK1527-E	250 pcs	Box (Tube)
	y- any	

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